Vishay Semiconductors

www.vishay.com

Hyperfast Rectifier, 60 A FRED Pt[®] G5



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS									
I _{F(AV)} 60 A									
V _R	1200 V								
V _F at I _F at 125 °C	1.7 V								
t _{rr}	38 ns								
T _J max.	175 °C								
Package	TO-247AD 2L								
Circuit configuration	Single								

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature FREE
- · Polyimide passivation
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: TO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating **Terminals**: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Repetitive peak reverse voltage	V _{RRM}		1200	V					
Average rectified forward current	I _{F(AV)}	T _C = 111 °C, D = 0.50	60						
Non-repetitive peak surge current	I _{FSM}	$T_C = 45$ °C, $t_p = 10$ ms, sine wave	425	A					
Repetitive peak forward current	I _{FRM}	T _C = 111 °C, D = 0.50, f = 20 kHz	120						
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C					

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)										
PARAMETER SYMBOL TEST CONDITIONS MIN. TYP. MAX. UNIT										
Breakdown voltage, blocking voltage		I _R = 100 μA	1200	-	-					
Forward voltage	V _F	I _F = 60 A	-	1.9	2.5	V				
Forward voltage		I _F = 60 A, T _J = 125 °C	-	1.7	-					
Deverse leekees eurrent	1	V _R = V _R rated	-	-	50					
Reverse leakage current	I _R	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA				
Junction capacitance C _T		V _R = 200 V	-	32	-	pF				
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH				

Revision: 09-Nov-2022

Document Number: 96766

1

HALOGEN

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



www.vishay.com

Vishay Semiconductors

DYNAMIC RECOVERY CHARACTERISTICS (T_J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
		I _F = 1.0 A, dI _F /dt =	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$			-			
Reverse recovery time	t _{rr}	T _J = 25 °C		-	130	-	ns		
		T _J = 125 °C		-	200	-			
Peak recovery current		T _J = 25 °C	I _F = 40 A dI _F /dt = 600 A/µs V _R = 400 V	-	22	-	A		
	I _{RRM}	T _J = 125 °C		-	39	-			
D	0	T _J = 25 °C		-	1610	-	nC		
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	4080	-			
Deveree receiver time		T _J = 25 °C		-	100	-	ns		
Reverse recovery time	t _{rr}	T _J = 125 °C		-	153	-			
Deals receiver a current		T _J = 25 °C	$I_{\rm F} = 60 {\rm A}$	-	40	-	A		
Peak recovery current	I _{RRM}	T _J = 125 °C	dl _F /dt = 1000 A/µs V _B = 800 V	-	67	-			
	0	T _J = 25 °C		-	2590	-	-0		
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	6150	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Thermal resistance, junction-to-case	R _{thJC}		-	-	0.4	°C/W				
Weight			-	5.5	-	g				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C				
Marking device		Case style TO-247AD 2L	E5PH6012LH							

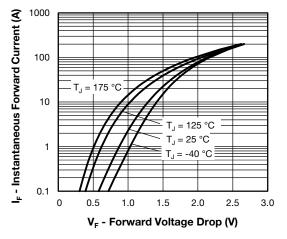


Fig. 1 - Typical Forward Voltage Drop Characteristics

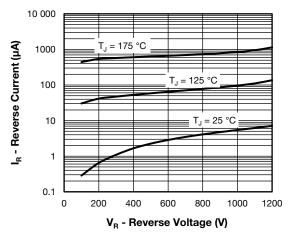
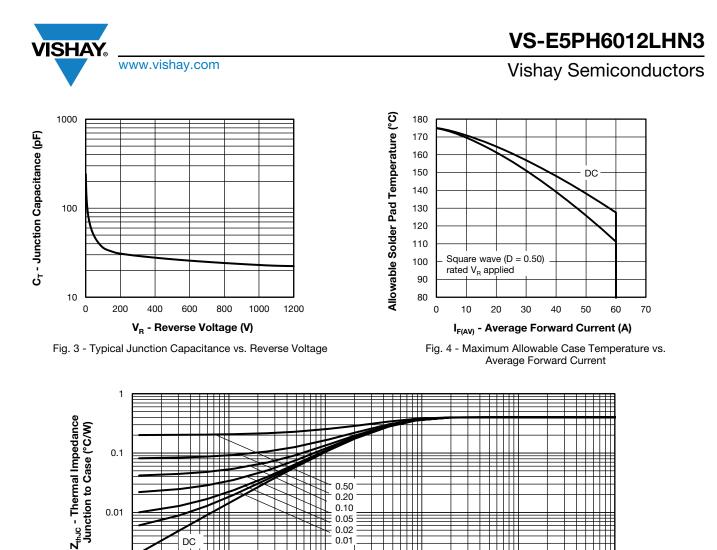


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



0.10

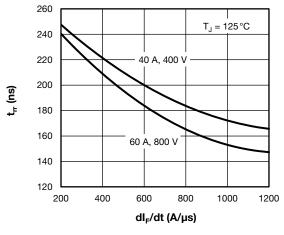
0.05 0.02

0.01

t₁ - Rectangular Pulse Duration (s) Fig. 5 - Thermal Impedance ZthJC Characteristics

0.001

0.01



DC

0.0001

0.01

0.001 0.00001

Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt

7000 T_J = 125 °C 6500 60 A. 800 V 6000 5500 Q_{rr} (nC) 5000 40 A, 400 V 4500 4000 3500 3000 200 400 600 800 1000 1200 dl_F/dt (A/µs)

0.1

1

Fig. 7 - Typical Stored Charge vs. dl_F/dt

Revision: 09-Nov-2022

3

Document Number: 96766

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

VS-E5PH6012LHN3

Vishay Semiconductors

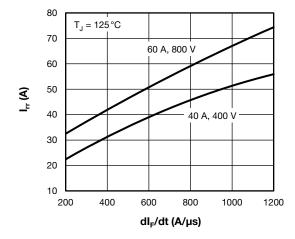


Fig. 8 - Typical Recovery Current vs. dl_F/dt

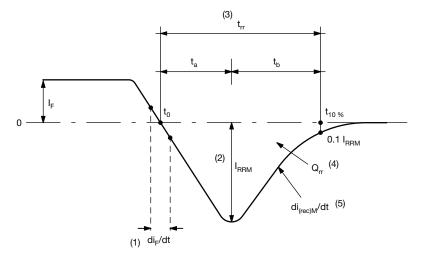


Fig. 9 - Reverse Recovery Waveform and Definitions

Notes

⁽¹⁾ di_F/dt - rate of change of current through zero crossing

www.vishay.com

- ⁽²⁾ I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM}
- $^{(4)}~~\text{Q}_{rr}$ area under curve defined by t_0 and $t_{10~\%}$

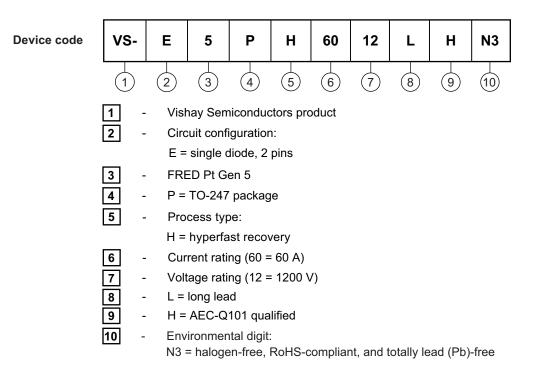
$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t)dt$$

⁽⁵⁾ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

Vishay Semiconductors

SHAY www.vishay.com

ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-E5PH6012LHN3	25	500	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95536						
Part marking information	www.vishay.com/doc?95648						
SPICE model	www.vishay.com/doc?97086						



Vishay Semiconductors

TO-247AD 2L

DIMENSIONS in millimeters and inches



Section C - C, D - D

(b. b2)

(4)

/	\square
	C C
Vie	<u>w B</u>

SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES	
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDUL	MIN.	MAX.	MIN.	MAX.	NUTES
А	4.65	5.31	0.183	0.209			Е	15.29	15.87	0.602	0.625	3
A1	2.21	2.59	0.087	0.102			E1	13.46	-	0.53	-	
A2	1.50	2.49	0.059	0.098			е	5.46	BSC	0.215	BSC	
b	0.99	1.40	0.039	0.055			ØК	0.2	254	0.0)10	
b1	0.99	1.35	0.039	0.053			L	19.81	20.32	0.780	0.800	
b2	1.65	2.39	0.065	0.094			L1	3.71	4.29	0.146	0.169	
b3	1.65	2.34	0.065	0.092			ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	BSC	
D2	0.51	1.35	0.020	0.053								

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

⁽²⁾ Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

(7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

Revision: 28-May-2018 Document Number: 95536 1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI Downloaded From Oneyac.com w.vishay.com/doc?91000



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2024 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jul-2024

1

单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)